TOSHIBA

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

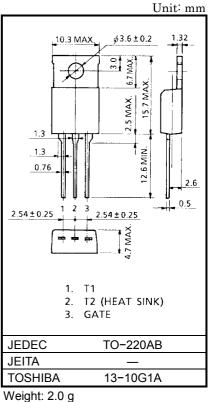
S6903G,S6903J

AC POWER CONTROL APPLICATIONS

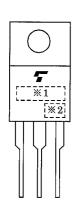
- High Rush Current Capability Optimal for controlling actuators where high rush current may flow. : $I_{TRM} = 120A$ (n = 100k cycle, Tc = 45°C)
- R.M.S On–State Current : IT (RMS) = 20A
- Repetitive Peak Off-State Voltage : VDRM = 400V, 600V

MAXIMUM RATINGS

CHARACTERI	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	S6903G	V _{DRM}	400	V	
	S6903J	VDRM	600	v	
R.M.S On-State Current (Full Sine Waveform Tc = 100°C)		I _{T (RMS)}	- (RMS) 20		
Peak One Cycle Surge On-State Current (Non-Repetitive)		le a c	180 (50Hz)	А	
		ITSM	200 (60Hz)	~	
Repetitive Surge On-Sta	ate Current (Note 1)	I _{TRM}	120	А	
I ² t Limit Value		l ² t	167	A ² s	
Critical Rate of Rise of On-State Current		di / dt	50	Α/μs	
Peak Gate Power Dissipation		P _{GM}	5	W	
Average Gate Power Dissipation		P _{G (AV)}	0.5	W	
Peak Gate Voltage		V _{GM}	10	V	
Peak Gate Current		I _{GM}	2	А	
Junction Temperature		Тj	-40~125	°C	
Storage Temperature Ra	ange	T _{stg}	-40~125	°C	



MARKING

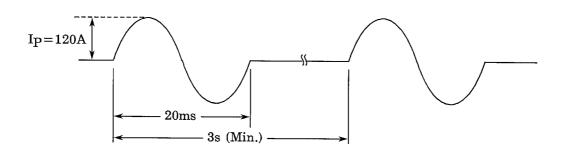


NUMBER	SYMBOL		MARK	
*1 T	TYPE	S6903G	S6903G	
		S6903J	S6903J	
*2	Year /Last I			

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		IDRM	V _{DRM} = Rated		—	_	20	μA
Gate Trigger Voltage	I	V _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	1.5	V
	Ш			T2 (+), Gate (−)	_	_	1.5	
	III			T2 (−), Gate (−)	_	_	1.5	
	IV			T2 (-), Gate (+)	_	_	_	
Gate Trigger Current	I	I _{GT}	V _D = 12V R _L = 20Ω	T2 (+), Gate (+)	_	_	30	mA
	Ш			T2 (+), Gate (−)	_	_	30	
	III			T2 (−), Gate (−)	_	_	30	
	IV			T2 (-), Gate (+)	_	_	—	
Peak On-State Voltage		V _{TM}	I _{TM} = 30A		_	_	1.6	V
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		Ι _Η	V _D = 12V, I _{TM} = 2A		_	_	50	mA
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC		—	—	1.0	°C/W
Critical Rate of Rise of Off-State Voltage at Commutation		(dv / dt) _c	V _{DRM} = 400V, T _j = 125°C (di / dt) c = -8.7A / ms		10	_	_	V /µs

Note 1: Repetitive Surge On-State Current



 I_P = 120A (f = 50Hz) at Tc = 45°C

Max. Repetitive Number of cycle n = 100k cycle (Repetitive cycle T = 3s Min.)

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